

DIGITRON SEMICONDUCTORS

1N3909-1N3913

FAST RECOVERY RECTIFIER

MAXIMUM RATINGS

Parameter	Symbol	1N3909	1N3910	1N3911	1N3912	1N3913
Working peak reverse voltage	V _{RM}	50V	100V	200V	300V	400V
Operating temperature range	T _J		-65 to +150°C			
Storage temperature range	T _{stg}		-65 to +175°C			
Maximum thermal resistance	R _{θJC}		0.8°C/W junction to case			
Mounting torque			25-30 inch pounds			
Weight			.54 ounces (15.3 grams) typical			

Add "R" to part numbers for reverse polarity.

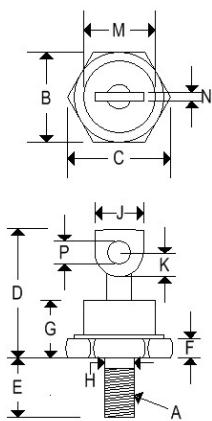
ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Value	Test Conditions
Average forward current	I _{F(AV)}	30 Amps	T _C = 100°C, square wave, R _{θJC} = 0.8°C/W
Maximum surge current	I _{FSM}	300 Amps	8.3ms, half-sine, T _C = 100°C
Maximum peak forward voltage	V _{FM}	1.40 Volts	I _{FM} = 50A; T _J = 25°C*
Maximum peak reverse current	I _{RM}	15 µA	V _{RRM} , T _J = 25°C
Maximum peak reverse current	I _{RM}	6.0 mA	V _{RRM} , T _J = 150°C
Maximum reverse recovery time	t _{RR}	200ns	I _F = 1A dc, V _R = 30V, di/dt = 25A/µs
Typical junction capacitance	C _J	130pF	V _R = 10V, f = 1Mhz, T _J = 25°C

* Pulse test: pulse width 300µsec. Duty cycle 2%

MECHANICAL CHARACTERISTICS

Case	DO-5(R)
Marking	Alpha-numeric
Normal polarity	Cathode is stud
Reverse polarity	Anode is stud (add "R" suffix)



	DO-5(R)			
	Inches		Millimeters	
	Min	Max	Min	Max
A	1/4-28 UNF2A threads			
B	0.669	0.688	16.990	17.480
C	-	0.794	-	20.160
D	-	1.000	-	25.400
E	0.422	0.453	10.720	11.510
F	0.115	0.200	2.920	5.080
G	-	0.450	-	11.430
H	0.220	0.249	5.580	6.320
J	0.250	0.375	6.350	9.530
K	0.156	-	3.960	-
M	-	0.667	-	16.940
N	0.030	0.080	0.760	2.030
P	0.140	0.175	3.560	4.450

Available Non-RoHS (standard) or RoHS compliant (add PBF suffix).

Available as "HR" (high reliability) screened per MIL-PRF-19500, JAN-TX level. Add "HR" suffix to base part number.

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Figure 1
Typical Forward Characteristics

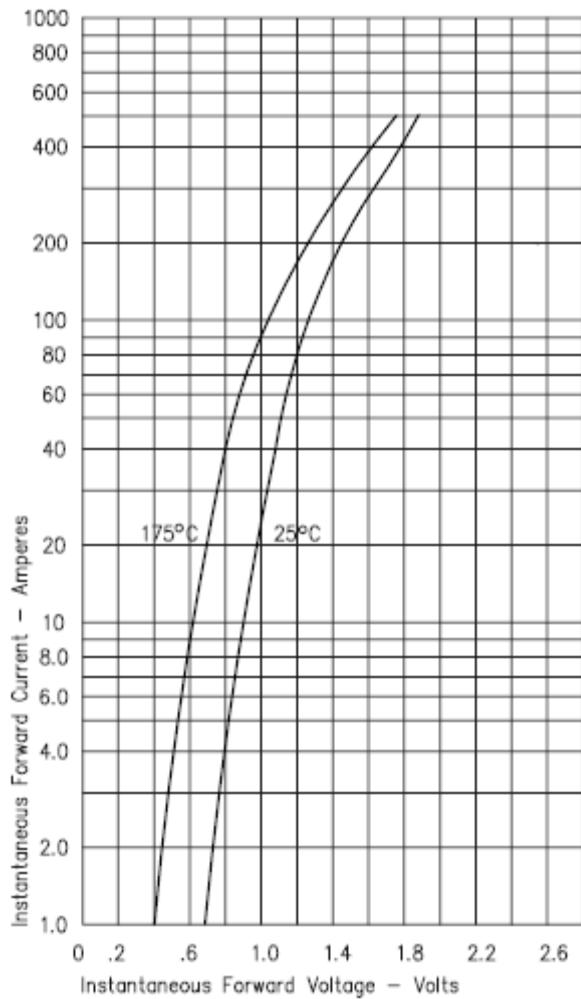


Figure 2
Typical Reverse Characteristics

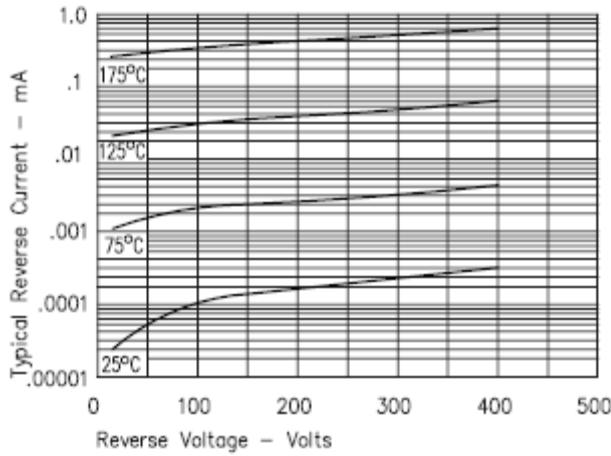


Figure 3
Typical Junction Capacitance

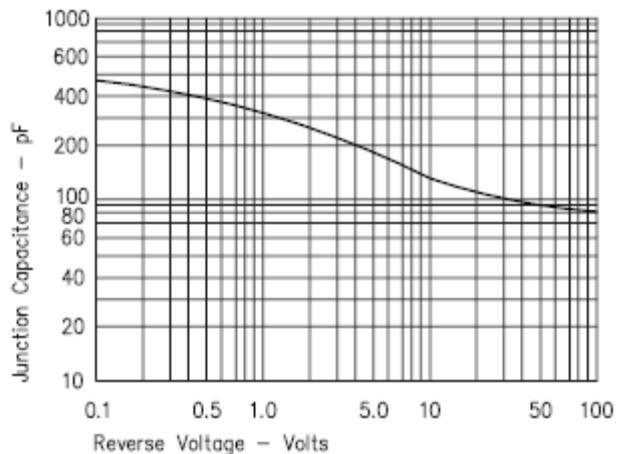


Figure 4
Forward Current Derating

